

# isc N-Channel MOSFET Transistor

# APT6015LVFR

#### **FEATURES**

- Drain Current –I<sub>D</sub>= 38A@ T<sub>C</sub>=25 °C
- · Drain Source Voltage-
  - : V<sub>DSS</sub>=600V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.15 \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **DESCRIPTION**

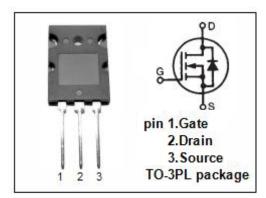
• Designed for use in switch mode power supplies and general purpose applications.

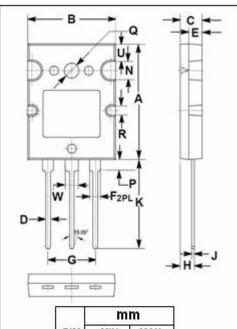
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{\text{DSS}}$	Drain-Source Voltage	600	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
ΙD	Drain Current-Continuous	38	А
I <sub>DM</sub>	Drain Current-Single Pluse	152	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	520	W
TJ	Max. Operating Junction Temperature -55~150		°C
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$ C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.24	°C/W





	mm		
DIM	MIN	MAX	
Α	25.50	26.50	
В	19.80	20.20	
C	4.50	5.50	
D	0.90	1.10	
E	2.80	3.20	
F	2.40	2.60	
G	10.80	11.00	
Н	3.10	3.30	
J	0.50	0.70	
K	20.00	21.00	
N	3.90	4.50	
Р	2.40	2.60	
Q	3.10	3.50	
R	1.90	2.60	
U	3.90	4.10	
W	2.90	3.25	



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	600		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 2.5mA	2	4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =19A		0.15	Ω
Igss	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 480V; V <sub>GS</sub> = 0@T <sub>C</sub> =125°C		250 1000	μА
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =-38A; V <sub>GS</sub> = 0		1.3	V

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